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MICROWAVE CORPORATION v00.1013



HMC641ALP4E

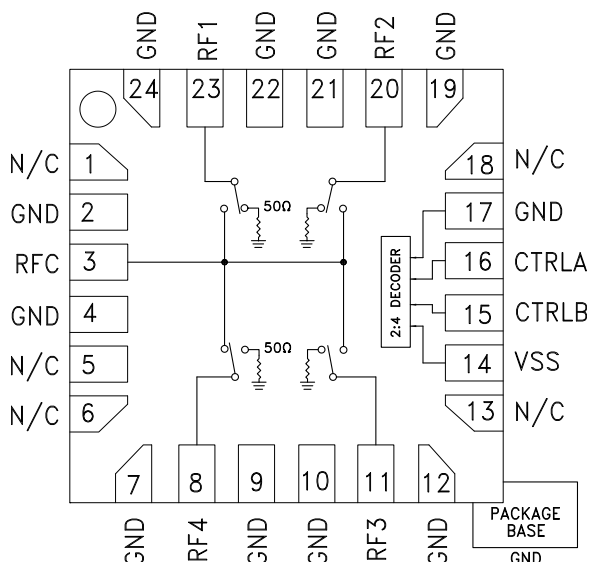
GaAs MMIC SP4T NON-REFLECTIVE SWITCH, DC - 20 GHz

Typical Applications

The HMC641ALP4E is ideal for:

- Telecom Infrastructure
- Microwave Radio & VSAT
- Military & Space Hybrids
- Test Instrumentation
- SATCOM & Sensors

Functional Diagram



Features

- Broadband Performance: DC - 20 GHz
- High Isolation: 45 dB @ 10 GHz
- Low Insertion Loss: 2.3 dB @ 10 GHz
- Integrated 2:4 TTL Decoder
- 24 Lead 4x4 mm SMT Package: 16 mm²

General Description

The HMC641ALP4E is a broadband non-reflective GaAs pHEMT SP4T switch in a compact 4x4 mm plastic package. Covering DC to 20 GHz, this switch offers high isolation, low insertion loss and on-chip termination of isolated ports. This switch also includes an on board binary decoder circuit which reduces the number of required logic control lines from four to two. The HMC641ALP4E is controlled with 0/-5V logic, exhibits fast switching speed and consumes much less DC current than pin diode based solutions.

Electrical Specifications, $T_A = +25^\circ\text{C}$, With 0/-5V Control, $V_{SS} = -5\text{V}$, 50 Ohm System

Parameter	Frequency	Min.	Typ.	Max.	Units
Insertion Loss	DC - 12 GHz		2.0	3.2	dB
	DC - 20 GHz		3.0	4.2	dB
Isolation (RFC to RF1 - RF4)	DC - 12 GHz	30	42		dB
	DC - 20 GHz	30	40		dB
Return Loss	DC - 12 GHz		18		dB
	DC - 20 GHz		17		dB
Return Loss	DC - 20 GHz		13		dB
Input Power for 1 dB Compression	0.05 - 0.25 GHz	15	20		dBm
	0.25 - 20 GHz	20	24		dBm
Input Third Order Intercept (Two-Tone Input Power= +10 dBm Each Tone)	0.05 - 0.25 GHz		30		dBm
	0.25 - 20 GHz		41		dBm
Switching Characteristics tRISE, tFALL (10/90% RF) tON, tOFF (50% CTL to 10/90% RF)	DC - 20 GHz		30		ns
			100		ns

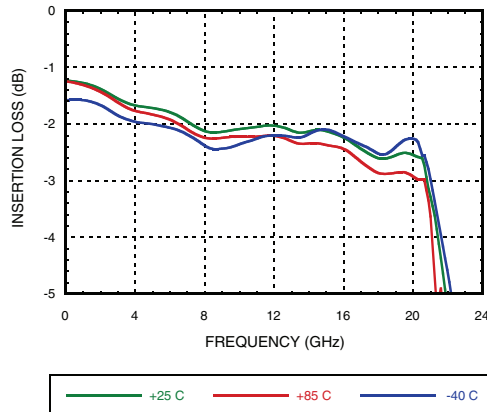
For price, delivery and to place orders: Hittite Microwave Corporation, 2 Elizabeth Drive, Chelmsford, MA 01824

Phone: 978-250-3343 Fax: 978-250-3373 Order On-line at www.hittite.com

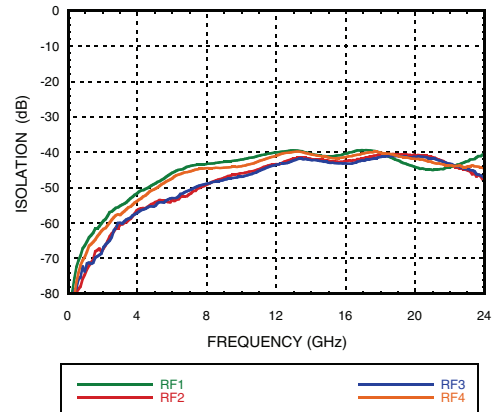
Application Support: Phone: 978-250-3343 or apps@hittite.com

GaAs MMIC SP4T NON-REFLECTIVE SWITCH, DC - 20 GHz

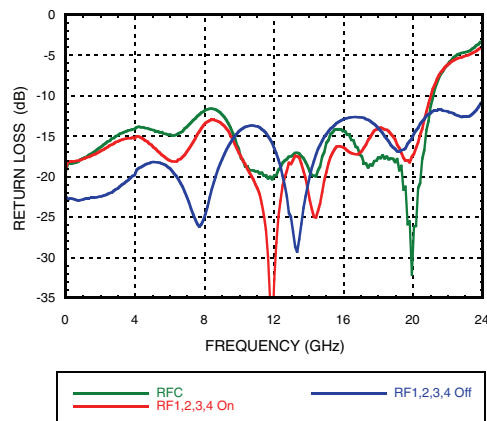
Insertion Loss vs. Temperature



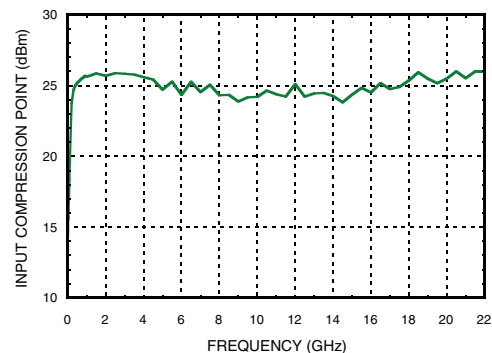
Isolation



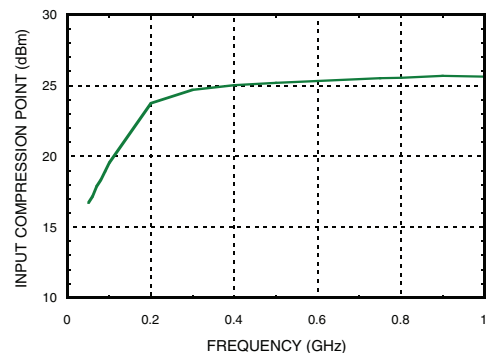
Return Loss



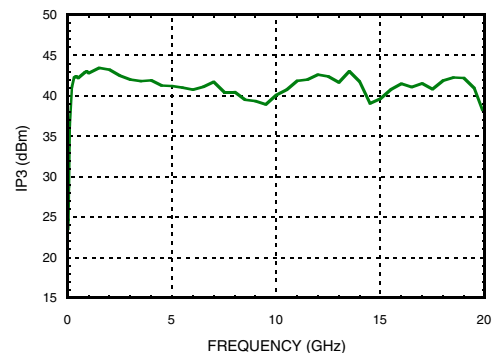
1 dB Input Compression Point



1 dB Input Compression Point (Low Frequency Detail)

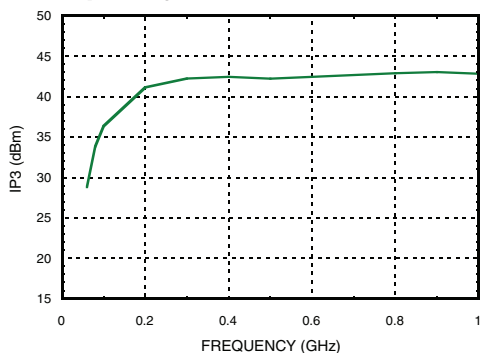


Input Third Order Intercept Point





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**HMC641ALP4E****GaAs MMIC SP4T NON-REFLECTIVE SWITCH, DC - 20 GHz****Input Third Order Intercept
(Low Frequency Detail)****Absolute Maximum Ratings**

Bias Voltage (Vss)	-7V
Control Voltage Range (CTRLA & CTRLB)	Vss -0.5V to +1V
Maximum Input Power	Insertion Loss Path Terminated Path
	+26.5 dBm +23 dBm
Channel Temperature	150 °C
Thermal Resistance	Insertion Loss Path Terminated Path
Channel to ground paddle	201 °C/W 321 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A

Truth Table

Control Input		Signal Path State
CTRLA	CTRLB	RFC to:
High	High	RF1
Low	High	RF2
High	Low	RF3
Low	Low	RF4

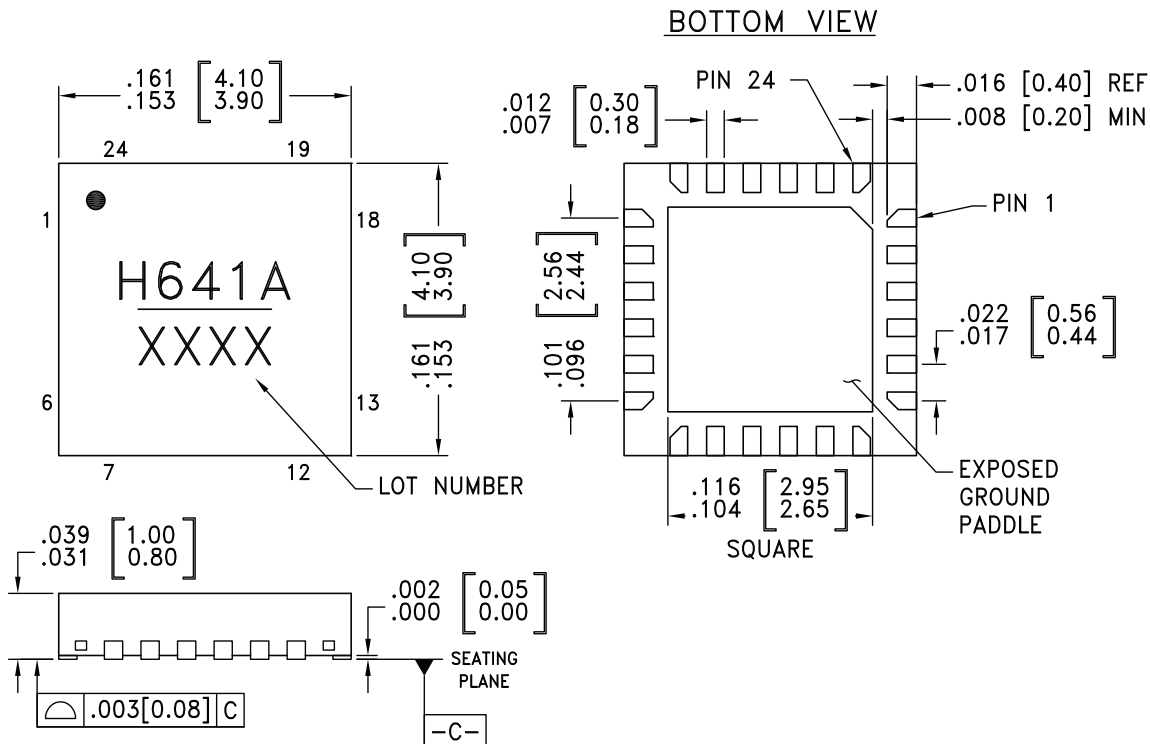
**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS****Bias Voltage & Current**

Vss Range = -5 Vdc $\pm$ 10%		
Vss (Vdc)	Iss (Typ) (mA)	Iss (Max) (mA)
-5	1.7	5.0

TTL/CMOS Control Voltages

State	Bias Condition
Low	-2.5V to 0V @ 30 μ A Typ.
High	-5V to -3.8V @ 0.5 μ A Typ.

Outline Drawing



NOTES:

1. LEADFRAME MATERIAL: COPPER ALLOY
2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE
4. PAD BURR LENGTH SHALL BE 0.15 mm MAXIMUM.
PAD BURR HEIGHT SHALL BE 0.05 mm MAXIMUM.
5. PACKAGE WARP SHALL NOT EXCEED 0.05 mm.
6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED LAND PATTERN.

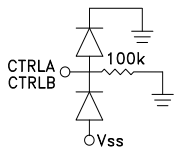
Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[1]
HMC641ALP4E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	H641A XXXX

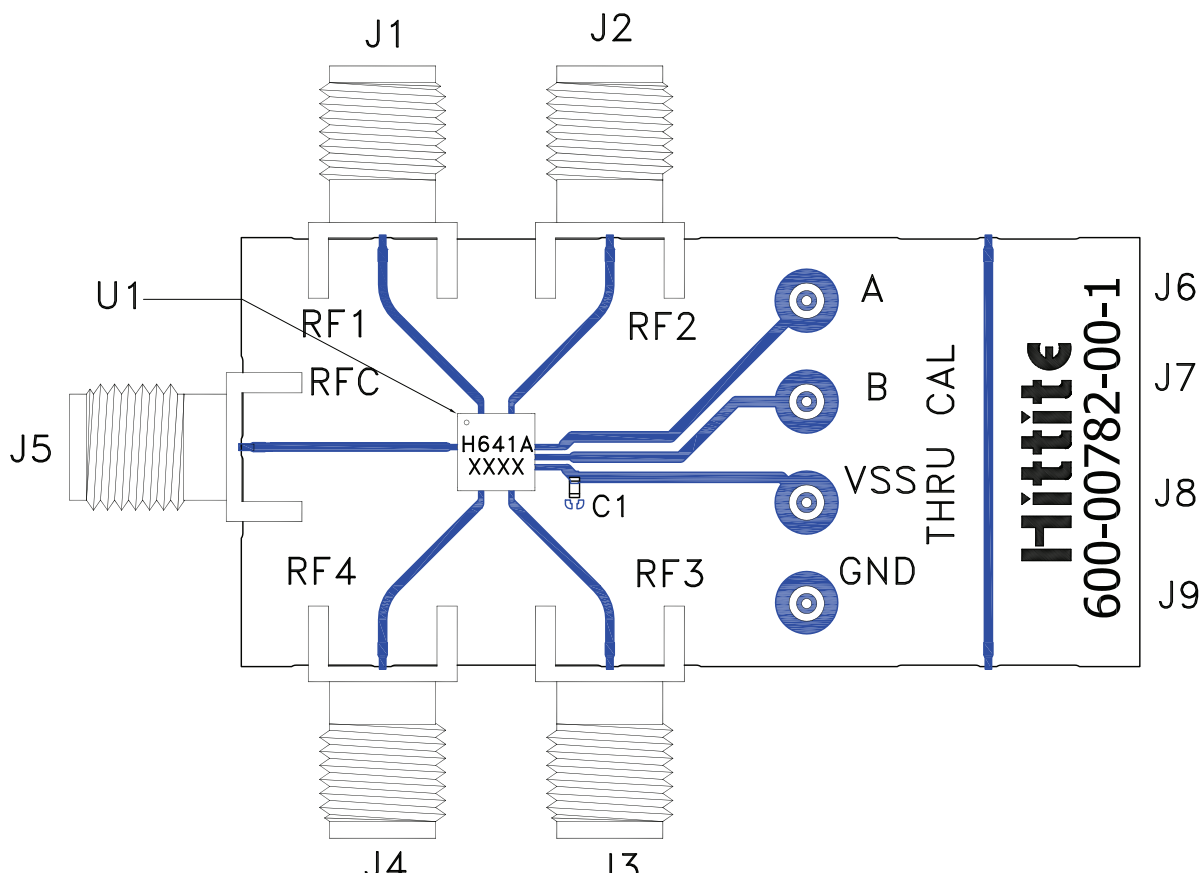
[1] 4-Digit lot number XXXX

[2] Max peak reflow temperature of 260 °C

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 5, 6, 13, 18	N/C	These pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
2, 4, 7, 9, 10, 12, 17, 19, 21, 22, 24 Ground Paddle	GND	These pins and the exposed ground paddle must be connected to RF/DC ground.	
3	RFC	This pin is DC coupled and matched to 50 Ohms. A blocking capacitor is required if RF line potential is not equal to 0V.	
8	RF4	This pin is DC coupled and matched to 50 Ohms. A blocking capacitor is required if RF line potential is not equal to 0V.	
11	RF3	This pin is DC coupled and matched to 50 Ohms. A blocking capacitor is required if RF line potential is not equal to 0V.	
14	Vss	Supply Voltage -5 Vdc $\pm$ 10%.	
15	CTRLB	See Truth Table and Control Voltage Table.	
16	CTRLA	See Truth Table and Control Voltage Table.	
20	RF2	This pin is DC coupled and matched to 50 Ohms. A blocking capacitor is required if RF line potential is not equal to 0V.	
23	RF1	This pin is DC coupled and matched to 50 Ohms. A blocking capacitor is required if RF line potential is not equal to 0V.	

Evaluation PCB



List of Materials for Evaluation PCB EVAL01-HMC641ALP4 [1]

Item	Description
J1 - J5	PCB Mount SMA Connector
J6 - J9	DC Pin
C1	1000 pF Capacitor, 0402 Pkg.
U1	HMC641ALP4E Switch
PCB [2]	600-00782-00-1 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350 or Arlon FR4

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.

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<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

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